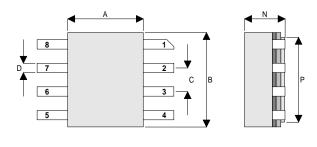
TetraFET

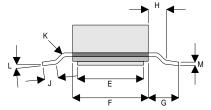
D2219UK



ROHS COMPLIANT METAL GATE RF SILICON FET

MECHANICAL DATA





SO8 PACKAGE

PIN 1 – SOURCE	PIN 5 – SOURCE
PIN 2 – DRAIN	PIN 6 – GATE
PIN 3 – DRAIN	PIN 7 – GATE
PIN 4 – SOURCE	PIN 8 – SOURCE

Dim.	mm	Tol.	Inches	Tol.	
Α	4.06	±0.08	0.160	±0.003	
В	5.08	±0.08	0.200	±0.003	
С	1.27	±0.08	0.050	±0.003	
D	0.51	±0.08	0.020	±0.003	
Е	3.56	±0.08	0.140	±0.003	
F	4.06	±0.08	0.160	±0.003	
G	1.65	±0.08	0.065	±0.003	
н	0.70	+0.25	0.020	+0.010	
п	0.76	-0.00	0.030	-0.000	
J	0.51	Min.	0.020	Min.	
J	1.02	Max.	0.040	Max.	
Κ	45°	Max.	45°	Max.	
I	0°	Min.	0°	Min.	
L	7°	Max.	7°	Max.	
М	0.20	±0.08	±0.08 0.008 ±0		
Ν	2.18	Max.	0.086	Max.	
Р	4.57	±0.08	0.180 ±0.00		

GOLD METALLISED MULTI-PURPOSE SILICON DMOS RF FET

2.5W – 12.5V – 1GHz SINGLE ENDED

FEATURES

- SIMPLIFIED AMPLIFIER DESIGN
- SUITABLE FOR BROAD BAND APPLICATIONS
- VERY LOW C_{rss}
- SIMPLE BIAS CIRCUITS
- LOW NOISE
- HIGH GAIN 10 dB MINIMUM

APPLICATIONS

• HF/VHF/UHF COMMUNICATIONS from 1 MHz to 1 GHz

ABSOLUTE MAXIMUM RATINGS (T_{case} = 25°C unless otherwise stated)

P _D	Power Dissipation	17.5W
BV _{DSS}	Drain – Source Breakdown Voltage	40V
BV _{GSS}	Gate – Source Breakdown Voltage	±20V
I _{D(sat)}	Drain Current	2A
T _{stg}	Storage Temperature	–65 to 150°C
Tj	Maximum Operating Junction Temperature	200°C

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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ELECTRICAL CHARACTERISTICS ($T_{case} = 25^{\circ}C$ unless otherwise stated)

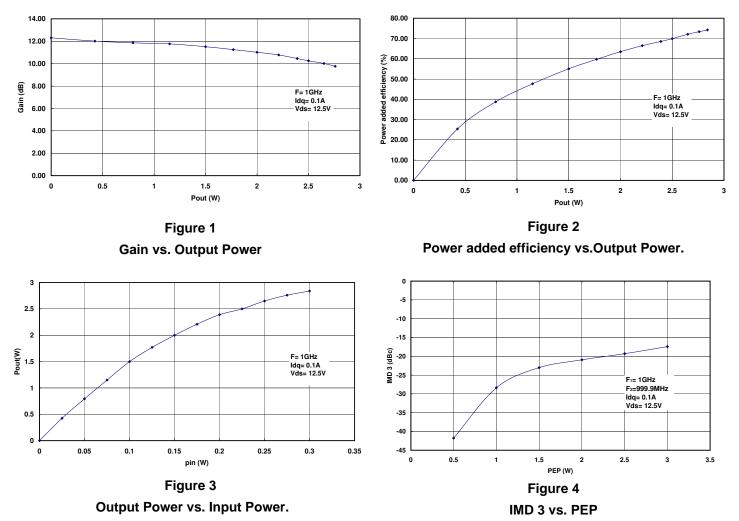
Parameter		Test Conditions			Min.	Тур.	Max.	Unit
B\/	Drain–Source	V _{GS} = 0	I	10mA	40			V
BV _{DSS}	Breakdown Voltage	VGS – 0	- D	= 10mA	40			v
1	Zero Gate Voltage	$V_{} = 125$	=\/ \/	0			1	mA
DSS	Drain Current	V _{DS} = 12.5\	V V _{GS}	= 0			I	IIIA
I _{GSS}	Gate Leakage Current	V _{GS} = 20V	V _{DS}	= 0			1	μΑ
V _{GS(th)}	Gate Threshold Voltage*	I _D = 10mA	V _{DS}	= V _{GS}	1		5	V
9fs	Forward Transconductance*	V _{DS} = 10V	I _D =	0.2A	0.18			S
G _{PS}	Common Source Power Gain	P _O = 2.5W			10			dB
η	Drain Efficiency	V _{DS} = 12.5\	√ I _{DQ}	= 0.1A	40			%
VSWR	Load Mismatch Tolerance	f = 1GHz			20:1			
C _{iss}	Input Capacitance	$V_{DS} = 0V$	$V_{GS} = -5V$	f = 1MHz			12	pF
C _{oss}	Output Capacitance	V _{DS} = 12.5V	$V_{GS} = 0$	f = 1MHz			10	pF
C _{rss}	Reverse Transfer Capacitance	V _{DS} = 12.5V	$V_{GS} = 0$	f = 1MHz			1	pF

* Pulse Test: Pulse Duration = 300 μs , Duty Cycle $\leq 2\%$

THERMAL DATA

R _{THj-case}	Thermal Resistance Junction – Case	Max. 10°C / W
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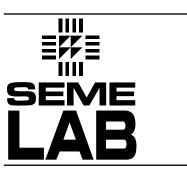


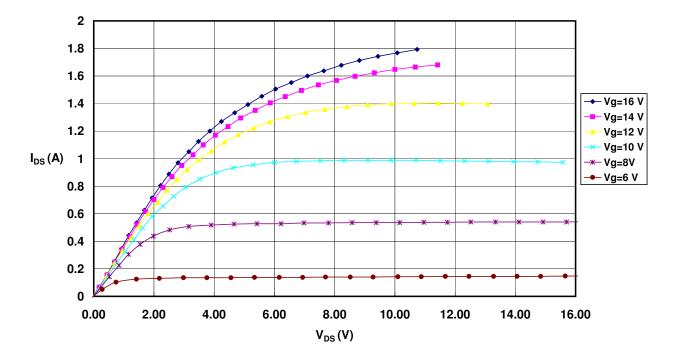


Typical S Parameters

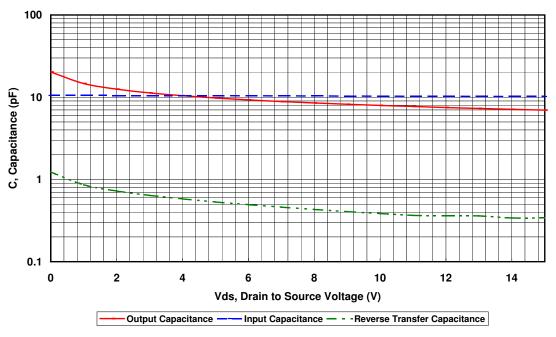
!D2219UK.s2p !Vds=12.5 , Idq=0.1 # MHz S MA R 50

Frequency	S11		S21		S12		S22	
MHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100	0.90	-52.39	14.50	138.14	0.03	51.05	0.83	-50.42
200	0.78	-87.99	10.45	110.84	0.05	26.61	0.73	-84.07
300	0.72	-111.57	7.68	91.95	0.05	10.36	0.69	-105.52
400	0.71	-127.63	5.88	78.13	0.05	1.04	0.69	-120.59
500	0.72	-140.52	4.61	66.59	0.04	-6.14	0.70	-132.26
600	0.73	-150.56	3.72	57.50	0.03	-8.39	0.73	-141.74
700	0.74	-159.64	3.09	48.88	0.03	-8.30	0.75	-150.19
800	0.77	-167.59	2.58	41.38	0.02	-2.44	0.77	-157.77
900	0.78	-175.33	2.18	34.32	0.02	10.50	0.80	-164.68
1000	0.80	-177.68	1.85	28.29	0.02	30.86	0.81	-170.86



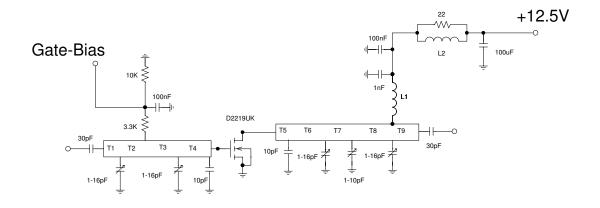












D2219UK 1GHz TEST FIXTURE

Substrate 0.8mm PTFE/glass, Er=2.5 All microstrip lines W=2.2mm

- T1 3mm T8 10mm
- T2 30mm T9 9mm
- T3 12mm
- T4 9mm
- T5 5mm
- T6 5 mm
- T7 15mm
- L1 7.5 turns 24swg enamelled copper wire, 3mm i.d.
- L2 1.5 turns 24swg enamelled copper wire on ferrite core

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